

# SHINDENGEN

## VX-2 Series Power MOSFET

N-Channel Enhancement type

**2SK2190  
(FP10W50VX2)**

**500V 10A**

### FEATURES

- Input capacitance ( $C_{iss}$ ) is small.  
Especially, input capacitance at 0 bias is small.
- The static  $R_{ds(on)}$  is small.
- The switching time is fast.

### APPLICATION

- Switching power supply of AC 100V input
- High voltage power supply
- Inverter

### RATINGS

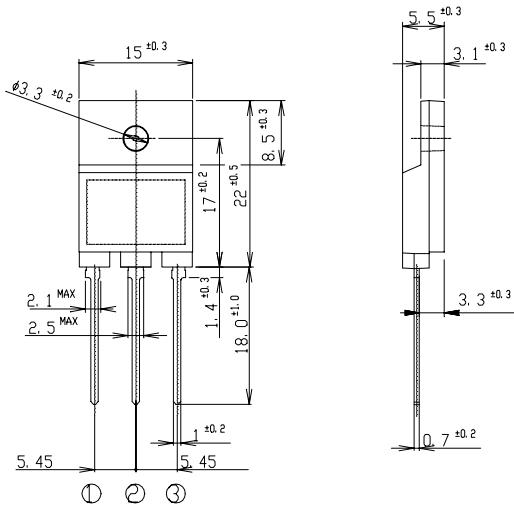
#### ● Absolute Maximum Ratings ( $T_c = 25^\circ\text{C}$ )

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	$T_{stg}$		-55~150	$^\circ\text{C}$
Channel Temperature	$T_{ch}$		150	
Drain-Source Voltage	$V_{DSS}$		500	V
Gate-Source Voltage	$V_{GSS}$		$\pm 30$	
Continuous Drain Current (DC)	$I_D$		10	A
Continuous Drain Current (Peak)	$I_{DP}$		30	
Continuous Source Current (DC)	$I_S$		10	
Total Power Dissipation	$P_T$		40	W
Single Pulse Avalanche Current	$I_{AS}$	$T_{ch} = 25^\circ\text{C}$	10	A
Dielectric Strength	$V_{dis}$	Terminals to case, AC 1 minute	2	kV
Mounting Torque	$T_{OR}$	( Recommended torque : 0.5N·m )	0.8	N·m

### OUTLINE DIMENSIONS

Case : ITO-3P

(Unit : mm)



①: G

②: D

③: S

## VX-2 Series Power MOSFET

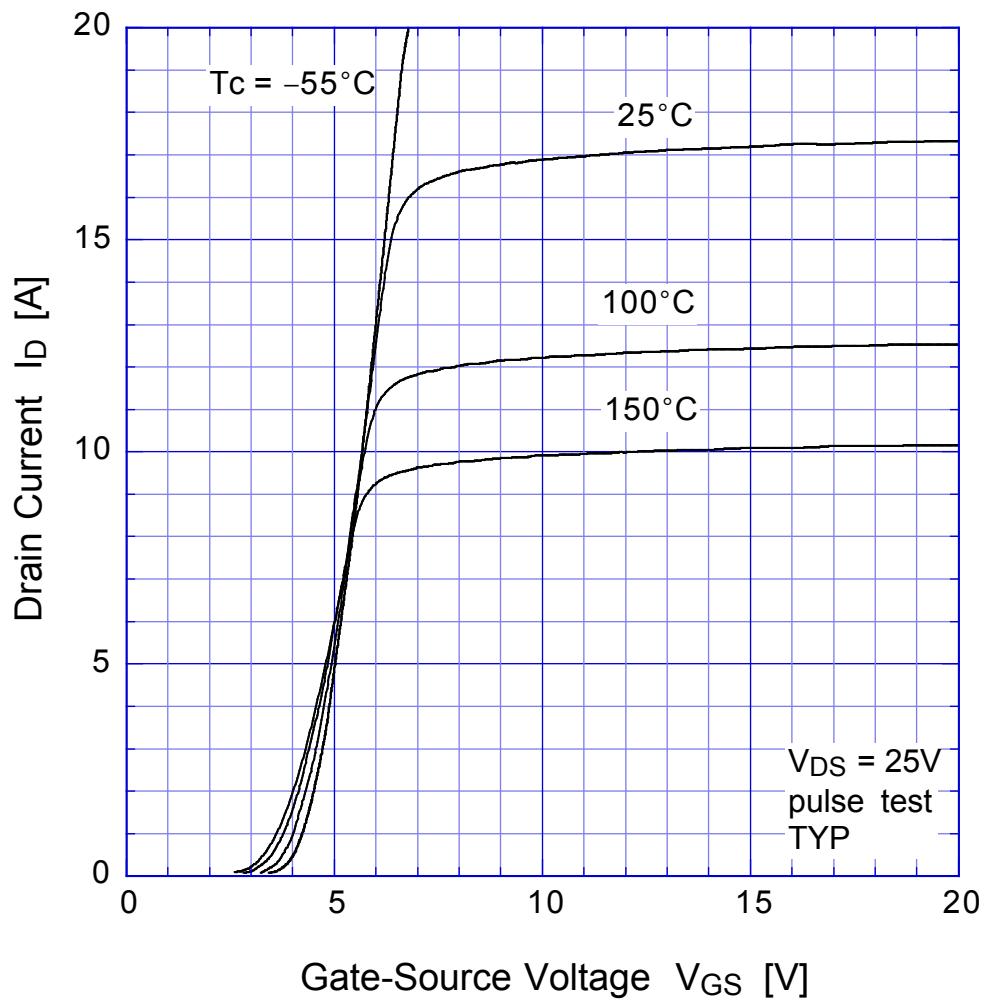
2SK2190( FP10W50VX2 )

### ●Electrical Characteristics Tc = 25°C

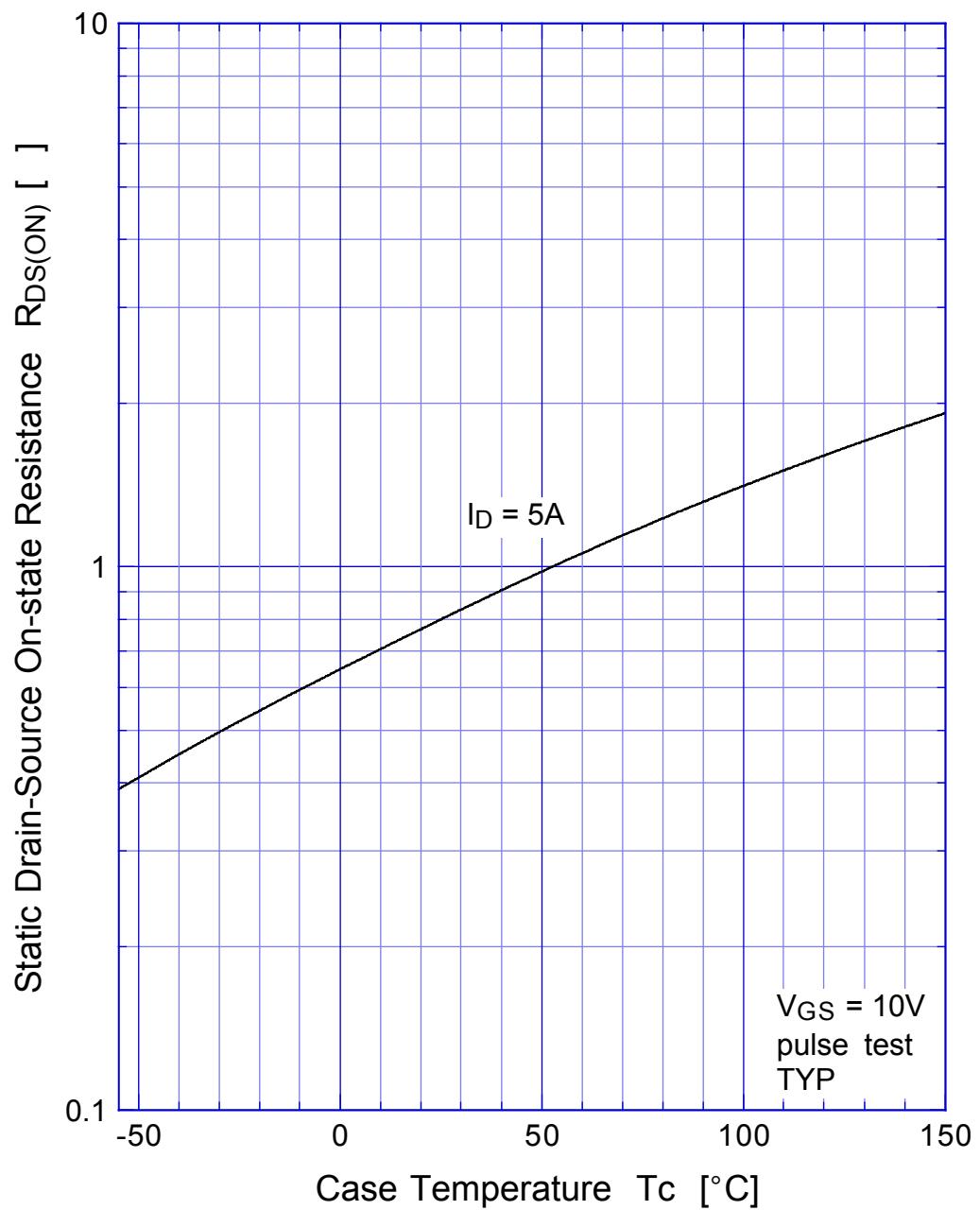
Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	V(BR)DSS	ID = 1mA, VGS = 0V	500			V
Zero Gate Voltage Drain Current	Idss	VDS = 500V, VGS = 0V			250	μ A
Gate-Source Leakage Current	IGSS	VGS = ±30V, VDS = 0V			±0.1	
Forward Transconductance	gfs	ID = 5A, VDS = 10V	2.4	6.3		S
Static Drain-Source On-state Resistance	RDS(ON)	ID = 5A, VGS = 10V		0.8	1.0	Ω
Gate Threshold Voltage	VTH	ID = 1mA, VDS = 10V	2.5	3.0	3.5	V
Source-Drain Diode Forwade Voltage	VSD	IS = 5A, VGS = 0V			1.5	
Thermal Resistance	θ jc	junction to case			3.12	°C/W
Total Gate Charge	Qg	VDD = 400V, VGS = 10V, ID = 10A		30		nC
Input Capacitance	Ciss	VDS = 10V, VGS = 0V, f = 1MHz		890		pF
Reverse Transfer Capacitance	Crss			70		
Output Capacitance	Coss			200		
Turn-On Time	ton	ID = 5A, VGS = 10V, RL = 30Ω		70	110	ns
Turn-Off Time	toff			140	220	

# 2SK2190

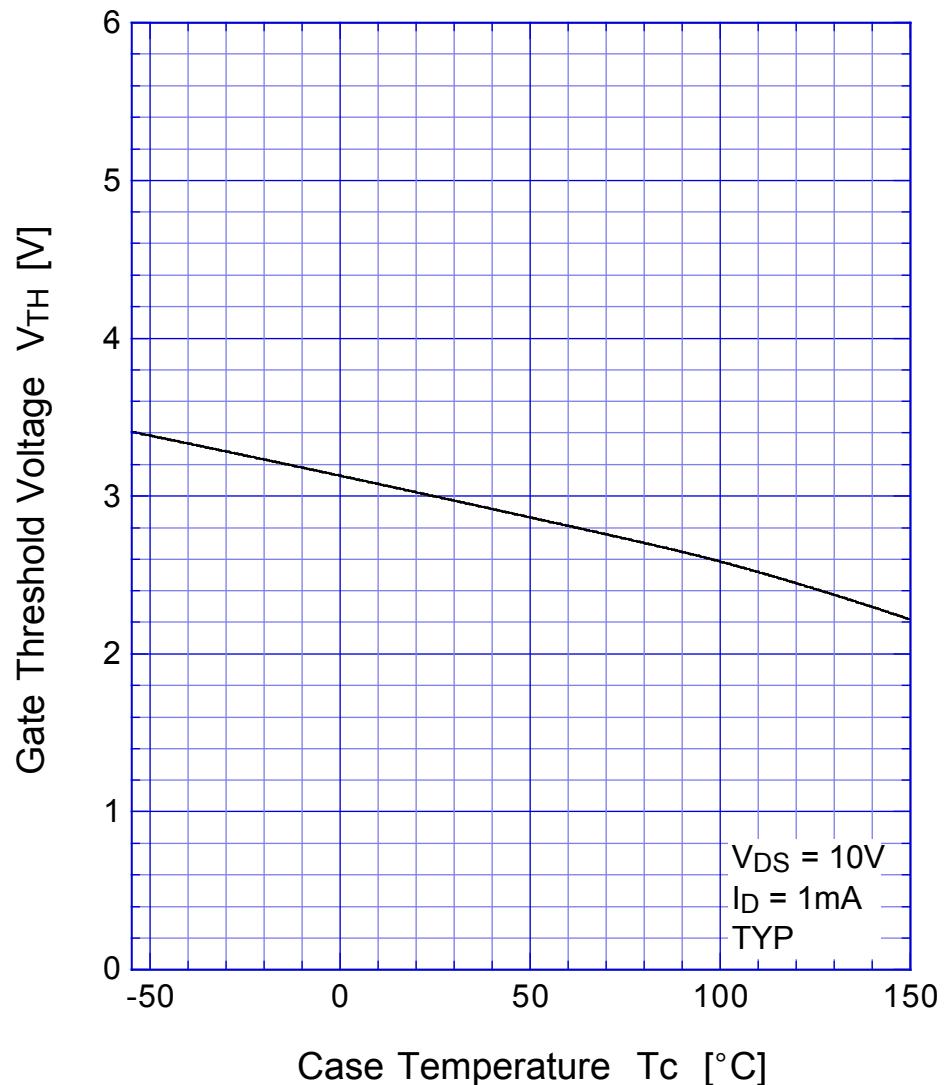
## Transfer Characteristics



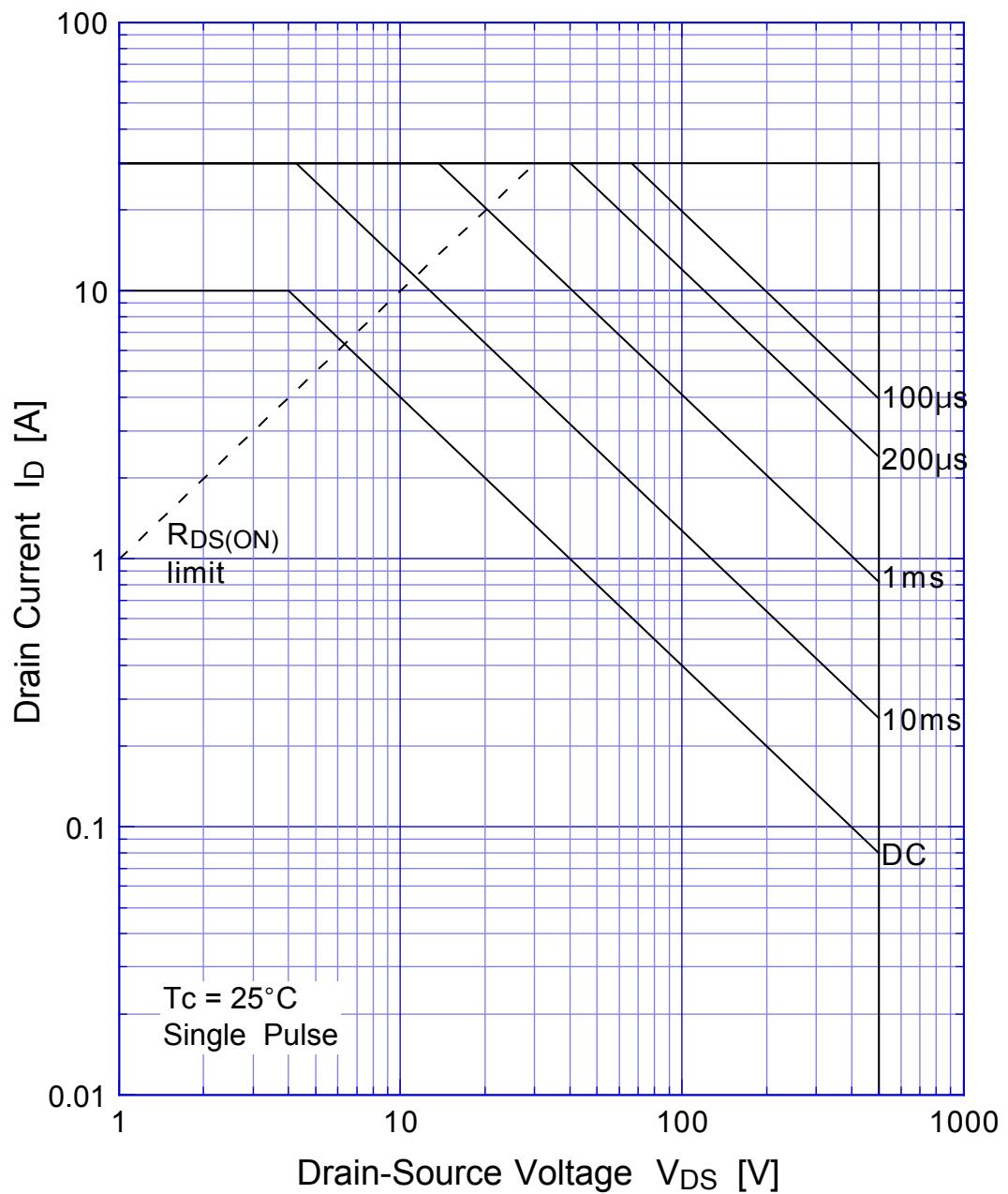
## **2SK2190 Static Drain-Source On-state Resistance**



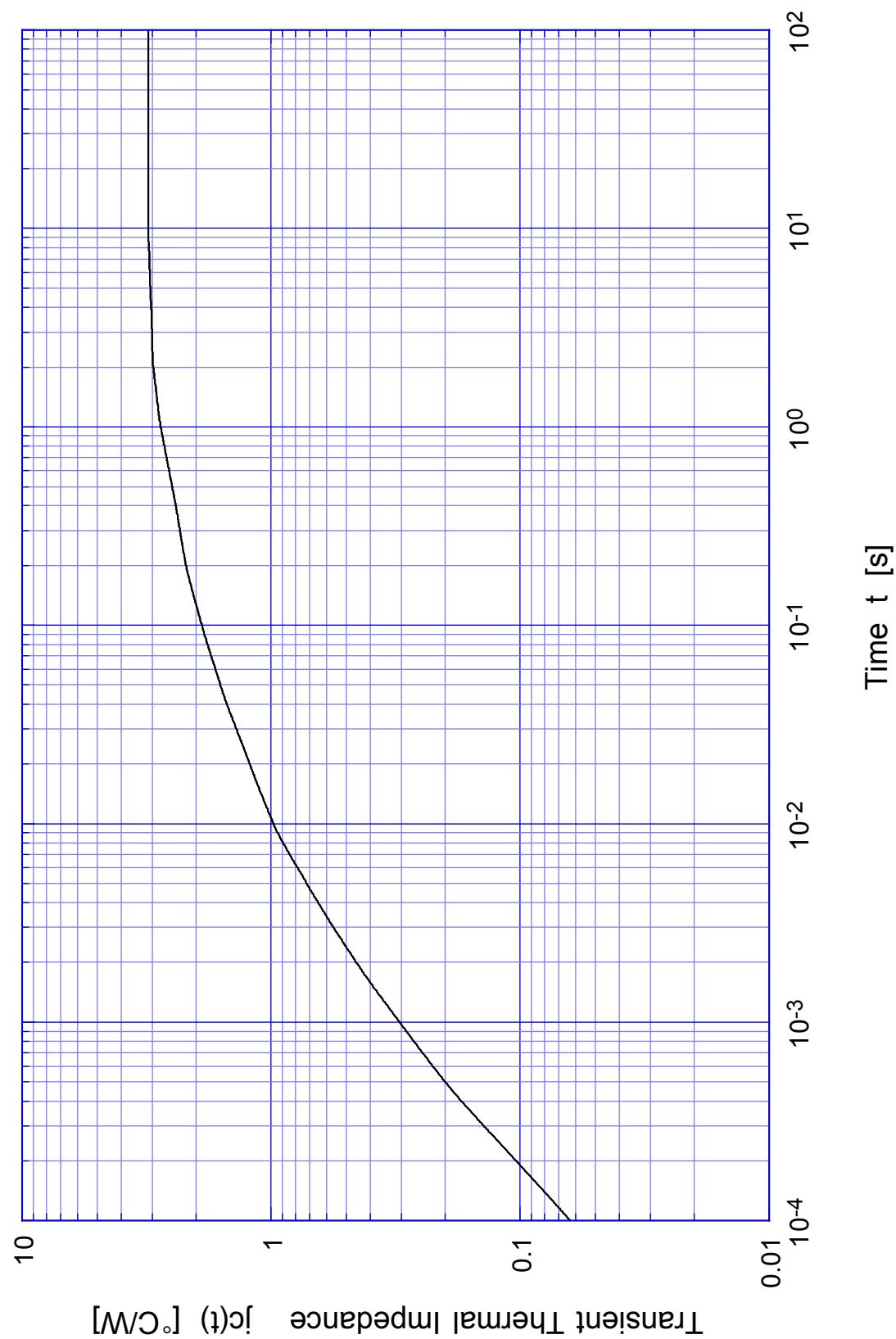
## 2SK2190 Gate Threshold Voltage



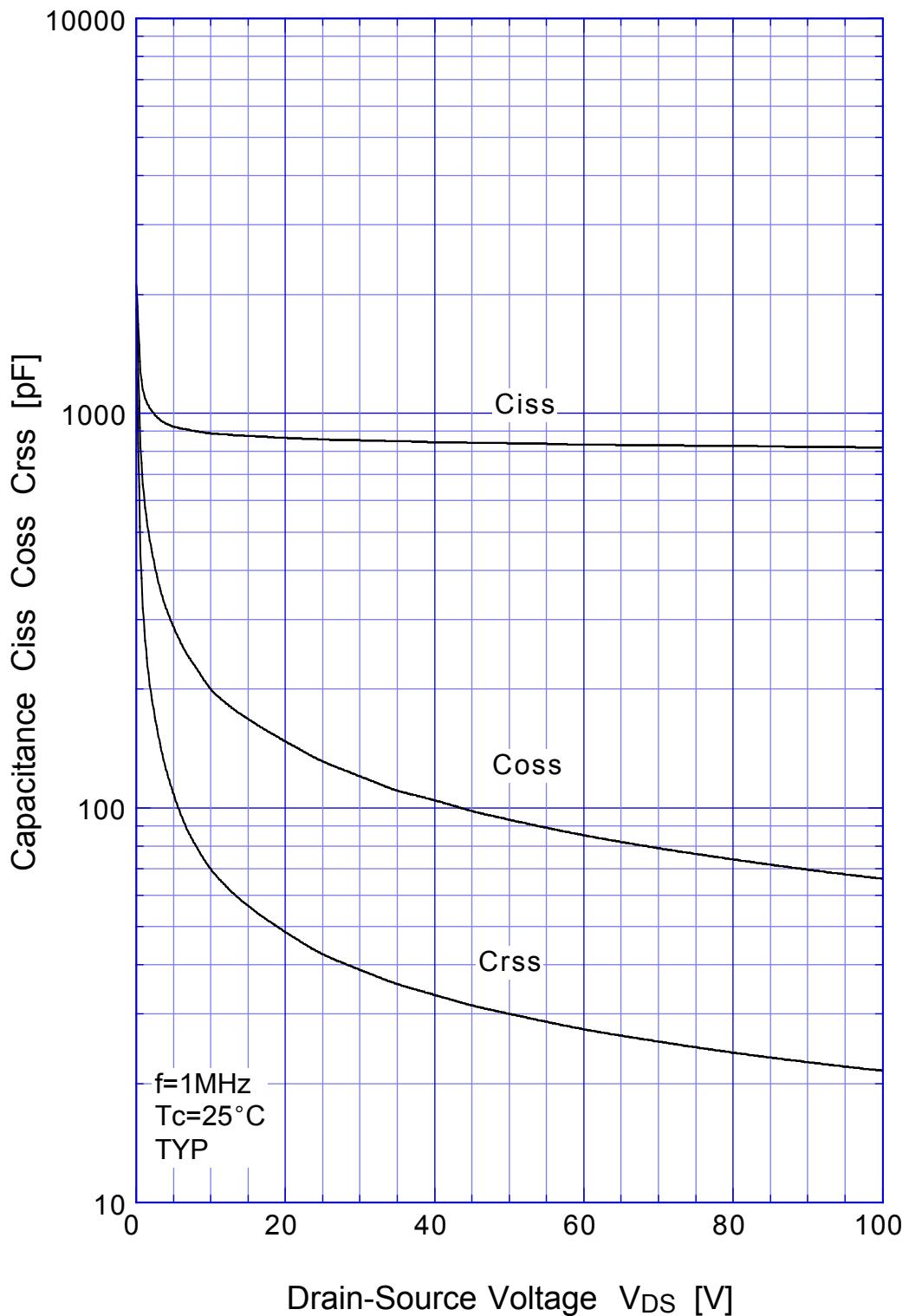
## 2SK2190 Safe Operating Area



## 2SK2190 Transient Thermal Impedance

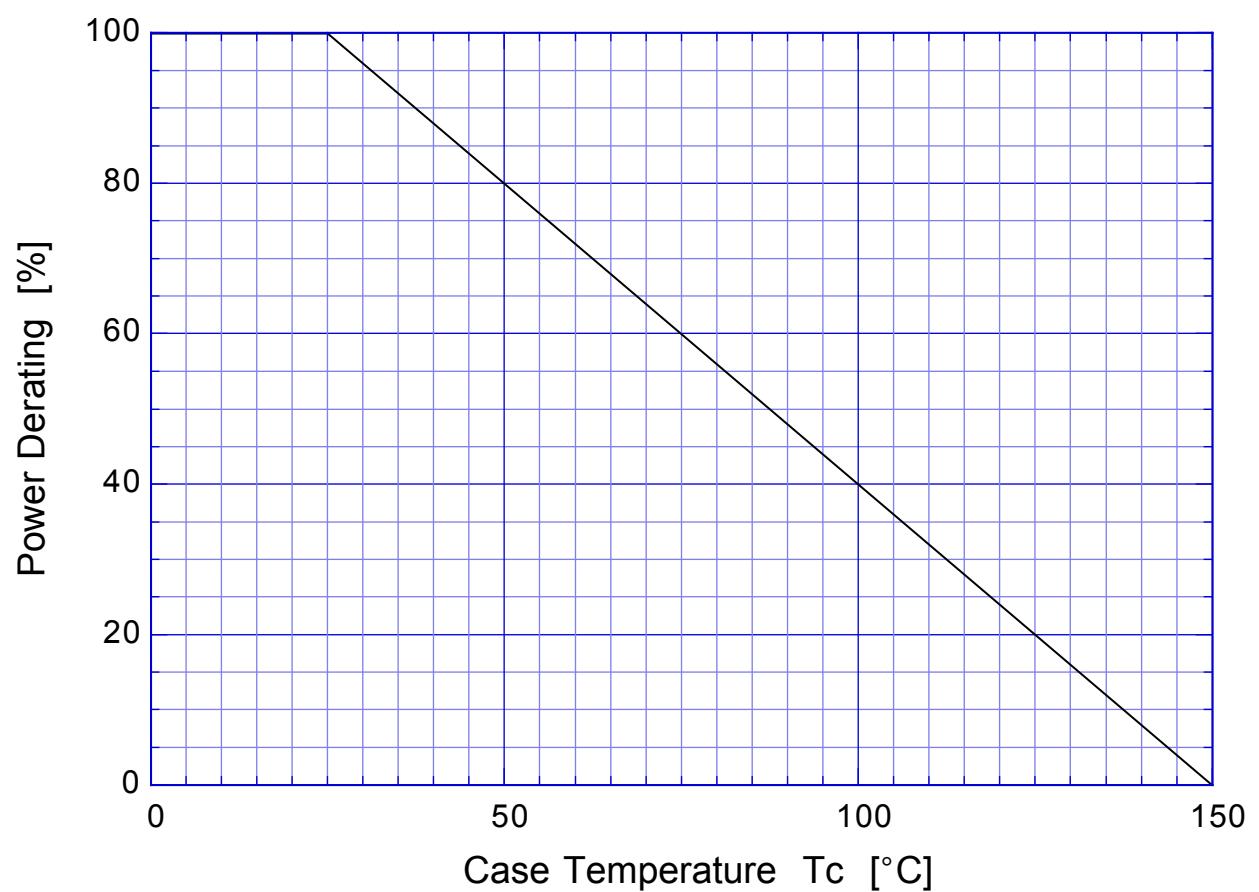


**2SK2190** Capacitance



**2SK2190**

Power Derating



## 2SK2190

### Gate Charge Characteristics

